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August 2014

FGA40N65SMD 650 V, 40 A Field Stop IGBT

Features

- Maximum Junction Temperature: T_J = 175°C
- · Positive Temperature Co-efficient for Easy Parallel Operating
- High Current Capability
- Low Saturation Voltage: $V_{CE(sat)} = 1.9 \text{ V(Typ.)} @ I_C = 40 \text{ A}$
- Fast Switching : E_{OFF} = 6.5 uJ/A
- · Tighten Parameter Distribution
- RoHS Compliant

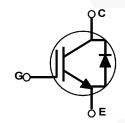
Applications

- · Solar Inverter, UPS, Welder, PFC, Induction Heating
- · Telecom, ESS

General Description

Using novel field stop IGBT technology, Fairchild's new series of field stop 2nd generation IGBTs offer the optimum performance for solar inverter, UPS, welder, induction heating, telecom, ESS and PFC applications where low conduction and switching losses are essential.





Absolute Maximum Ratings

Symbol	Description		Ratings	Unit
V _{CES}	Collector to Emitter Voltage		650	V
V _{GES}	Gate to Emitter Voltage		± 20	V
* GES	Transient Gate to Emitter Voltage		± 30	V
Ic	Collector Current	@ T _C = 25°C	80	А
·C	Collector Current	@ T _C = 100°C	40	А
I _{CM (1)}	Pulsed Collector Current		120	А
I _F	Diode Forward Current	@ T _C = 25°C	40	А
	Diode Forward Current	@ T _C = 100°C	20	Α
I _{FM (1)}	Pulsed Diode Maximum Forward Curren	120	Α	
P _D	Maximum Power Dissipation	@ T _C = 25°C	349	W
гD	Maximum Power Dissipation	@ T _C = 100°C	174	W
T _J	Operating Junction Temperature		-55 to +175	°C
T _{stg}	Storage Temperature Range		-55 to +175	°C
T _L	Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 seconds		300	°C

Notes

1: Repetitive rating: Pulse width limited by max. junction temperature

Thermal Characteristics

Symbol	Parameter	Тур.	Max.	Unit
$R_{\theta JC}(IGBT)$	Thermal Resistance, Junction to Case	-	0.43	°C/W
$R_{\theta JC}(Diode)$	Thermal Resistance, Junction to Case	-	1.5	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	-	40	°C/W

Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FGA40N65SMD	FGA40N65SMD	TO-3PN	Tube	N/A	N/A	30

Electrical Characteristics of the IGBT $T_C = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Off Charac	eteristics					
BV _{CES}	Collector to Emitter Breakdown Voltage	$V_{GE} = 0 \text{ V}, I_{C} = 250 \mu\text{A}$	650	-	-	V
$\frac{\Delta BV_{CES}}{\Delta T_{J}}$	Temperature Coefficient of Breakdown Voltage	V_{GE} = 0 V, I_{C} = 250 μ A	-	0.6	-	V/°C
I _{CES}	Collector Cut-Off Current	V _{CE} = V _{CES} , V _{GE} = 0 V	-\	-	250	μА
I _{GES}	G-E Leakage Current	$V_{GE} = V_{GES}, V_{CE} = 0 V$	-	_	±400	nA
On Charac	teristics					
V _{GE(th)}	G-E Threshold Voltage	I _C = 250 μA, V _{CE} = V _{GE}	3.5	4.5	6.0	V
		I _C = 40 A, V _{GE} = 15 V	-	1.9	2.5	V
V _{CE(sat)} Collector to Emitter Saturation Volta		I _C = 40 A, V _{GE} = 15 V, T _C = 175°C	-	2.1	-	V
Dynamic C	Characteristics					
C _{ies}	Input Capacitance		-	1880	-	pF
C _{oes}	Output Capacitance	V _{CE} = 30 V _, V _{GE} = 0 V, f = 1 MHz	-	180	-	pF
C _{res}	Reverse Transfer Capacitance	-1 - 1 1011112	-	50	-	pF
Switching	Characteristics		7			
t _{d(on)}	Turn-On Delay Time		-/	12	16	ns
t _r	Rise Time		-	20	28	ns
t _{d(off)}	Turn-Off Delay Time	$V_{CC} = 400 \text{ V}, I_{C} = 40 \text{ A},$	-	92	120	ns
t _f	Fall Time	$R_G = 6 \Omega$, $V_{GE} = 15 V$,	-	13	17	ns
E _{on}	Turn-On Switching Loss	Inductive Load, T _C = 25°C	-	0.82	1.23	mJ
E _{off}	Turn-Off Switching Loss		-	0.26	0.34	mJ
E _{ts}	Total Switching Loss		-	1.08	1.57	mJ
t _{d(on)}	Turn-On Delay Time		-	15	- \	ns
t _r	Rise Time		_	22	-	ns
t _{d(off)}	Turn-Off Delay Time	$V_{CC} = 400 \text{ V}, I_{C} = 40 \text{ A},$ $R_{G} = 6 \Omega, V_{GE} = 15 \text{ V},$	-	116	-	ns
t _f	Fall Time		-	16	-	ns
E _{on}	Turn-On Switching Loss	Inductive Load, T _C = 175°C	-	1.08	-	mJ
E _{off}	Turn-Off Switching Loss		-	0.60	-	mJ
E _{ts}	Total Switching Loss			1.68		mJ

Electrical Characteristics of the IGBT (Continued)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max	Unit
Q_g	Total Gate Charge		-	119	180	nC
Q _{ge}	Gate to Emitter Charge	V _{CE} = 400 V, I _C = 40 A, V _{GE} = 15 V	-	13	20	nC
Q _{gc}	Gate to Collector Charge	VGE - 10 V	-	58	90	nC

Electrical Characteristics of the Diode T_C = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions		Min.	Тур.	Max	Unit
V _{FM}	Diode Forward Voltage	I _F = 20 A	T _C = 25°C	-	2.1	2.6	V
* FIM	Diode Fermana Venage	F 2071	T _C = 175°C	-	1.7	-	
E _{rec}	Reverse Recovery Energy		T _C = 175°C	-	96	-	uJ
t	t _{rr} Diode Reverse Recovery Time	I _F =20 A, di _F /dt = 200 A/μs	T _C = 25°C	-	42	-	ns
भा			T _C = 175°C	-	200	-	
I	Diode Peak Reverse Recovery Current		T _C = 25°C	-	3.6	-	Α
·IT			T _C = 175°C	-	8.0	-	, ,
O	Q _{rr} Diode Reverse Recovery Charge		$T_{\rm C} = 25^{\rm o}{\rm C}$	-	76	-	nC
~11			T _C = 175°C	-	800	-	

Figure 1. Typical Output Characteristics

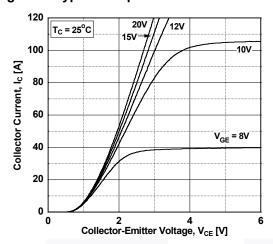


Figure 3. Typical Saturation Voltage Characteristics

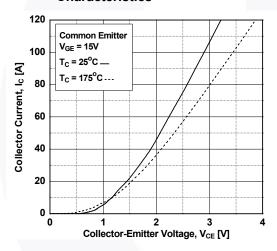


Figure 5. Saturation Voltage vs. V_{GE}

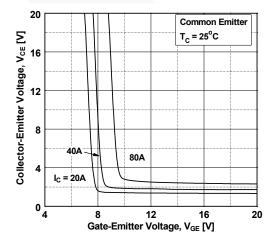


Figure 2. Typical Output Characteristics

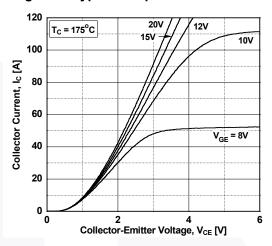


Figure 4. Saturation Voltage vs. Case
Temperature at Variant Current Level

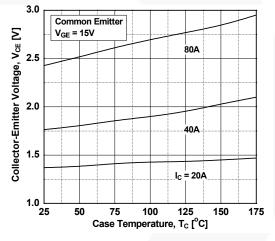


Figure 6. Saturation Voltage vs. V_{GE}

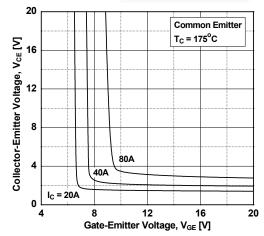


Figure 7. Capacitance Characteristics

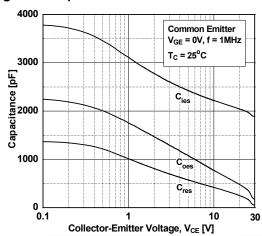


Figure 9. Turn-on Characteristics vs.
Gate Resistance

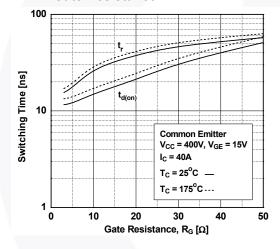


Figure 11. Switching Loss vs.
Gate Resistance

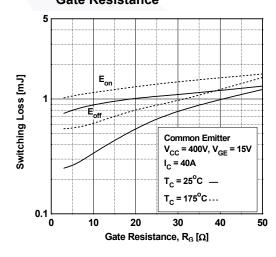


Figure 8. Gate charge Characteristics

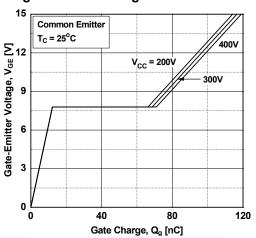


Figure 10. Turn-off Characteristics vs. Gate Resistance

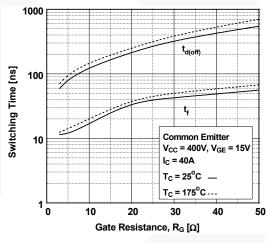


Figure 12. Turn-on Characteristics vs. Collector Current

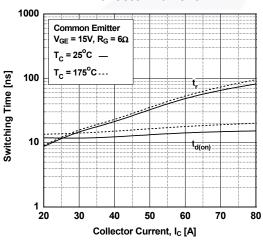


Figure 13. Turn-off Characteristics vs. Collector Current

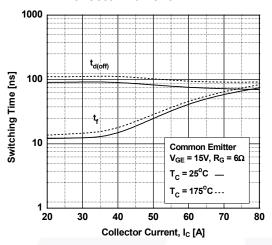


Figure 14. Switching Loss vs. Collector Current

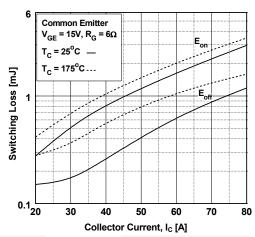


Figure 15. Load Current vs. Frequency

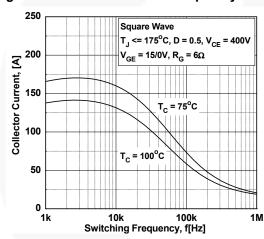


Figure 16. SOA Characteristics

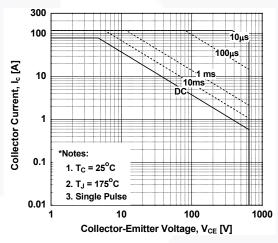


Figure 17. Forward Characteristics

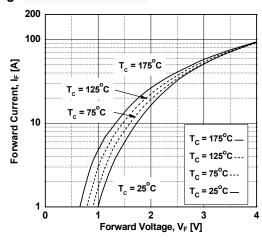


Figure 18. Reverse Recovery Current

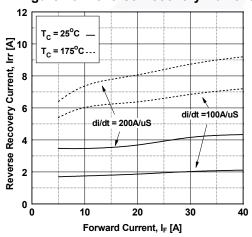


Figure 19. Reverse Recovery Time

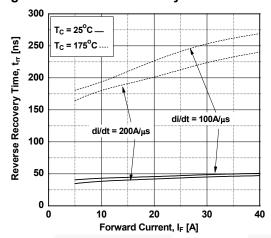


Figure 20. Stored Charge

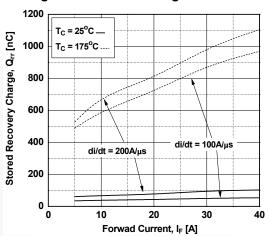


Figure 21. Transient Thermal Impedance of IGBT

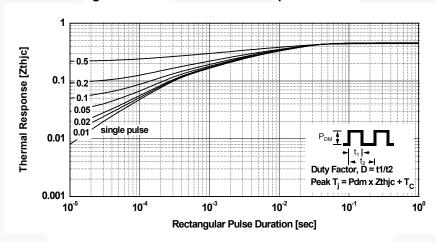
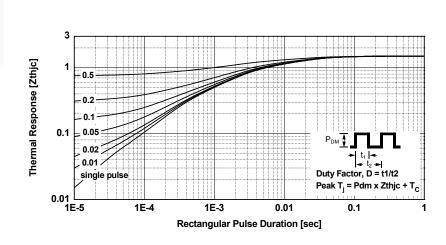
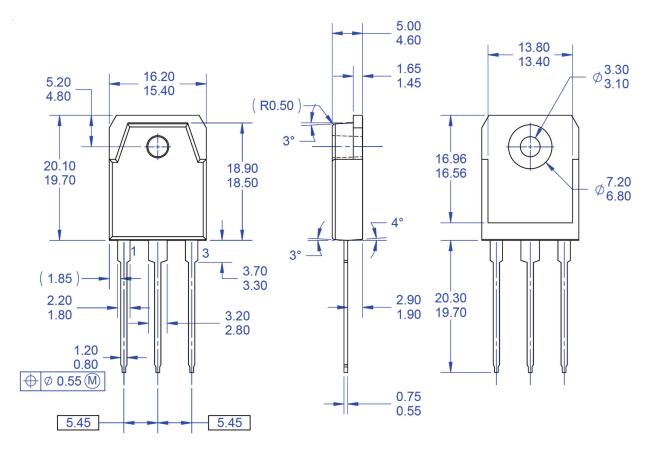


Figure 22. Transient Thermal Impedance of Diode



Mechanical Dimensions



(R0.50)

- NOTES: UNLESS OTHERWISE SPECIFIED
- A) THIS PACKAGE CONFORMS TO EIAJ SC-65 PACKAGING STANDARD.
- ALL DIMENSIONS ARE IN MILLIMETERS.
- DIMENSION AND TOLERANCING PER ASME14.5-2009.
- D) DIMENSIONS ARE EXCLUSSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSSIONS. DRAWING FILE NAME: TO3PN03AREV1.
- FAIRCHILD SEMICONDUCTOR.

Figure 23. TO-3P 3L - 3LD, T03, PLASTIC, EIAJ SC-65

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